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PARUL UNIVERSITY
FACULTY OF ENGINEERING \& TECHNOLOGY
B.Tech. Summer 2018-19 Examination

Semester: 3
Date: 28/05/2019
Subject Code: 03107201
Time: 02:00pm to 04:30pm
Subject Name: Advanced Analog Electronics
Total Marks: 60

## Instructions:

1. All questions are compulsory.
2. Figures to the right indicate full marks.
3. Make suitable assumptions wherever necessary.
4. Start new question on new page.
Q. 1 Objective Type Questions - ( Fill in the blanks, one word answer, MCQ-not more than Five in case of MCQ) (All are compulsory) (Each of one mark)
5. State various resistances and capacitances in the hybrid $\pi$ model.
6. What is the maximum efficiency of a class B circuit?
a) $90 \%$
b) $78.5 \%$
c) $50 \%$
d) $25 \%$
7. Which type of power amplifier is biased for operation at less than $360^{\circ}$ of the cycle?
8. The gate of JFET is $\qquad$ biased.
a) forward
b) reverse
c) forward
d) reverse as well as forward
e) none of above
9. A JFET has three terminals, namely...
a) cathode, anode, grid
b) source, gate ,drain
c) emitter, base, collector
d) none of the above
10. Draw symbol of P Channel E-MOSFET
7.State type of feedback used in the oscillator circuits?
11. Write the formula of Gain with feedback for voltage shunt feedback connection
12. Draw the symbol of N Channel D - MOSFET
13. Define Pinch-off voltage with reference to JFET
14. What is the main difference between E-MOSFET and D-MOSFET?
15. Write the drain current equation for JFET.
13.A MOSFET is sometimes called $\qquad$ JFET
a) many gate
b) open gate
c) insulated gate
d) shorted gate
16. Which of the following oscillator is RC type:
a) Clapp
b) Hartley
c) Colpitt's
d) Phase Shift
17. The expression for frequency of oscillations of a RC phase shift oscillator is
a) $\mathrm{f}=1 /(2 \pi \sqrt{ } \mathrm{RC})$
b) $\mathrm{f}=1 /(2 \pi \sqrt{ } \mathrm{R}(\mathrm{C} 1+\mathrm{C} 2))$
c) $\mathrm{f}=1 /(2 \pi \mathrm{RC} \sqrt{ } 6)$
d) none of the above
Q. 2 Answer the following questions. (Attempt any three)
A) Obtain trans conductance value for Ic equal to 10 mA .
B) (i) A class A transformer-coupled class A amplifier uses a 25:1 transformer to drive a 4 ohm load. Calculate the effective ac load. (ii) What transformer turns ratio required to match 16 ohm speaker load so that effective resistance seen at the primary is 10 K ohm.
C) Draw the AC equivalent circuit for JFET. What is the value of constant ' $k$ ' in E-MOSFET when $\mathrm{V}_{\mathrm{GS}(\mathrm{ON})}=8 \mathrm{~V}, \mathrm{I}_{\mathrm{D}(\mathrm{ON})}=10 \mathrm{~mA}, \mathrm{~V}_{\mathrm{GS}(\mathrm{TH})}=2 \mathrm{~V}$.
D) Derive the formula for trans-conductance $\mathrm{g}_{\mathrm{m}}$ in FET using mathematical approach and shockley's equation.
Q. 3 A) Draw the voltage series feedback connection. Also derive the input impedance \& output impedance.
B)State \& Derive BarkHausen criterion required for oscillation
B) A transistor has following parameters at Ic $=10 \mathrm{~mA}$, hie $=1 \mathrm{~K} \Omega$, hre $=2 * 10^{-4}$, hfe $=100$, hoe $=4 * 10^{5} \mathrm{~A} / \mathrm{V}$. Calculate (i) gm (ii) rb'e (iii) rbb' (iv) rb'c
Q. 4 A) Explain the operation of class B Push Pull amplifier with circuit.
A) Draw the VDB circuit for JFET. Also find $\mathrm{Z}_{\mathrm{l}}, \mathrm{Z}_{\mathrm{O}}$ and $\mathrm{A}_{\mathrm{V}}$
B) Determine the following parameters for the network given in the following figure.

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\mathrm{V}_{\mathrm{GSQ}}, \mathrm{I}_{\mathrm{DQ}}, \mathrm{~V}_{\mathrm{DS}}, \mathrm{~V}_{\mathrm{D}}, \mathrm{~V}_{\mathrm{G}}, \mathrm{~V}_{\mathrm{S}}
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